

SPECIFICATIONS

Customer		
Product Name	整流二极管	
Oyd Part	OYDUS1A-OYDUS1M	
Package	DO-214AC	

Approved By	Checked By	Issued By
		縣岩膏

Shenzhen Ouyada Electronics Co., Ltd.

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Approved By	Verified By	Re-checked By	Checked By
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mments:			



OYDUS1A THRU OYDUS1M



FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
 High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AC molded plastic body Terminals: Solder plated, solderable per MIL-STD-750, Method 2026 Polarity: Color band denotes cathode end Mounting Position: Any Weight: 0.003 ounce, 0.093 grams

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	OYDUS1A	OYDUS18	OYDUS1D	OYDUS1G	OYDUS1J	OYDUS1K	OYDUS1M	UNITS
Maximum repetitive peak reverse voltage		50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage		35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage		50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current		10						Amp	
at T⊾=110 C		1.0							
Peak forward surge current									
8.3ms single half sine-wave superimposed on			30.0					Amps	
rated load (JEDEC Method)									
Maximum instantaneous forward voltage at 1.0A	Vf				1.1				Volts
Maximum DC reverse current TA=25 C		5.0							
at rated DC blocking voltage Ta=100 C	IR	50.0							uA
Typical junction capacitance (NOTE 1)		15.0					pF		
Typical thermal resistance (NOTE 2)		75.0					C/W		
Operating junction and storage temperature range		-65 to +175					С		

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas



OYDUS1A THRU OYDUS1M



AMBIENT TEMPERATURE,°C

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLEAGE, VOLTS

FIG. 5-TYPICAL JUNCTION CAPACITANCE





NUMBER OF CYCLES AT 60 Hz

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE,%

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



t,PULSE DURATION,sec.